

## 54AC258 • 54ACT258 Quad 2-Input Multiplexer with TRI-STATE® Outputs

### General Description

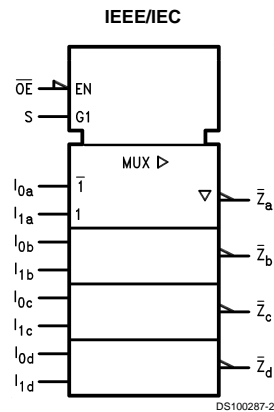
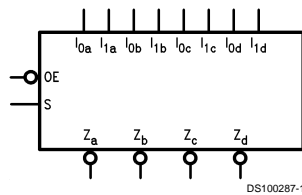
The 'AC/ACT258 is a quad 2-input multiplexer with TRI-STATE outputs. Four bits of data from two sources can be selected using a common data select input. The four outputs present the selected data in the complement (inverted) form. The outputs may be switched to a high impedance state with a HIGH on the common Output Enable ( $\overline{OE}$ ) input, allowing the outputs to interface directly with bus-oriented systems.

- Multiplexer expansion by tying outputs together
- Inverting TRI-STATE outputs
- Outputs source/sink 24 mA
- 'ACT258 has TTL-compatible inputs
- Standard Military Drawing (SMD)
  - 'ACT258: 5962-88704
  - 'AC258: 5962-91604

### Features

- $I_{CC}$  and  $I_{OZ}$  reduced by 50%

### Logic Symbols

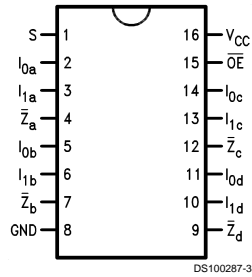


Pin Names	Description
S	Common Data Select Input
$\overline{OE}$	TRI-STATE Output Enable Input
$I_{0a}-I_{0d}$	Data Inputs from Source 0
$I_{1a}-I_{1d}$	Data Inputs from Source 1
$\overline{Z}_a-\overline{Z}_d$	TRI-STATE Inverting Data Outputs

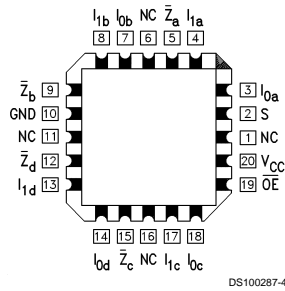
TRI-STATE® is a registered trademark of National Semiconductor Corporation.  
FACT® is a registered trademark of Fairchild Semiconductor Corporation.

## Connection Diagrams

Pin Assignment  
for DIP and Flatpak



Pin Assignment  
for LCC



## Functional Description

The 'AC/ACT258 is a quad 2-input multiplexer with TRI-STATE outputs. It selects four bits of data from two sources under control of a common Select input (S). When the Select input is LOW, the  $I_{0x}$  inputs are selected and when Select is HIGH, the  $I_{1x}$  inputs are selected. The data on the selected inputs appears at the outputs in inverted form. The 'AC/ACT258 is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

$$\bar{Z}_a = \overline{OE} \cdot (I_{1a} \cdot S + I_{0a} \cdot \bar{S})$$

$$\bar{Z}_b = \overline{OE} \cdot (I_{1b} \cdot S + I_{0b} \cdot \bar{S})$$

$$\bar{Z}_c = \overline{OE} \cdot (I_{1c} \cdot S + I_{0c} \cdot \bar{S})$$

$$\bar{Z}_d = \overline{OE} \cdot (I_{1d} \cdot S + I_{0d} \cdot \bar{S})$$

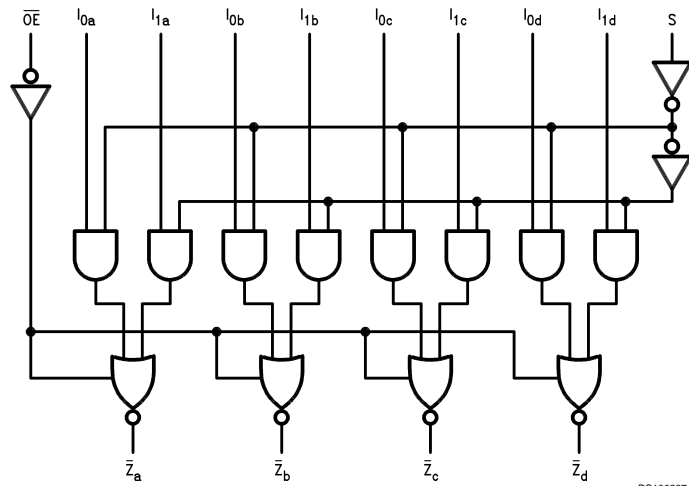
When the Output Enable input ( $\overline{OE}$ ) is HIGH, the outputs are forced to a high impedance state. If the outputs of the TRI-STATE devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to TRI-STATE devices whose outputs are tied together are designed so there is no overlap.

## Truth Table

Output Enable	Select Input	Data Inputs		Outputs
$\overline{OE}$	S	$I_0$	$I_1$	$\bar{Z}$
H	X	X	X	Z
L	H	X	L	H
L	H	X	H	L
L	L	L	X	H
L	L	H	X	L

H = HIGH Voltage Level  
L = LOW Voltage Level  
X = Immaterial  
Z = High Impedance

## Logic Diagram



DS100287-5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

## Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage ( $V_{CC}$ )	-0.5V to +7.0V
DC Input Diode Current ( $I_{IK}$ )	
$V_I = -0.5V$	-20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage ( $V_I$ )	-0.5V to $V_{CC} + 0.5V$
DC Output Diode Current ( $I_{OK}$ )	
$V_O = -0.5V$	-20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage ( $V_O$ )	-0.5V to $V_{CC} + 0.5V$
DC Output Source or Sink Current ( $I_O$ )	$\pm 50$ mA
DC $V_{CC}$ or Ground Current per Output Pin ( $I_{CC}$ or $I_{GND}$ )	$\pm 50$ mA
Storage Temperature ( $T_{STG}$ )	-65°C to +150°C
Junction Temperature ( $T_J$ )	
CDIP	175°C

## Recommended Operating Conditions

Supply Voltage ( $V_{CC}$ )	
'AC	2.0V to 6.0V
'ACT	4.5V to 5.5V
Input Voltage ( $V_I$ )	0V to $V_{CC}$
Output Voltage ( $V_O$ )	0V to $V_{CC}$
Operating Temperature ( $T_A$ )	
54AC/ACT	-55°C to +125°C
Minimum Input Edge Rate ( $\Delta V/\Delta t$ )	
'AC Devices	
$V_{IN}$ from 30% to 70% of $V_{CC}$	
$V_{CC}$ @ 3.3V 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ( $\Delta V/\Delta t$ )	
'ACT Devices	
$V_{IN}$ from 0.8V to 2.0V	
$V_{CC}$ @ 4.5V, 5.5V	125 mV/ns

**Note 1:** Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT® circuits outside databook specifications.

## DC Characteristics for 'AC Family Devices

Symbol	Parameter	$V_{CC}$ (V)	54AC	Units	Conditions	
			$T_A = -55^\circ\text{C to } +125^\circ\text{C}$			
			Guaranteed Limits			
$V_{IH}$	Minimum High Level Input Voltage	3.0	2.1	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$	
		4.5	3.15			
		5.5	3.85			
$V_{IL}$	Maximum Low Level Input Voltage	3.0	0.9	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$	
		4.5	1.35			
		5.5	1.65			
$V_{OH}$	Minimum High Level Output Voltage	3.0	2.9	V	$I_{OUT} = -50 \mu A$	
		4.5	4.4			
		5.5	5.4			
			3.0	2.4	V	(Note 2) $V_{IN} = V_{IL}$ or $V_{IH}$ $I_{OH} = -12 \text{ mA}$ $I_{OH} = -24 \text{ mA}$ $I_{OH} = -24 \text{ mA}$
			4.5	3.7		
			5.5	4.7		
$V_{OL}$	Maximum Low Level Output Voltage	3.0	0.1	V	$I_{OUT} = 50 \mu A$	
		4.5	0.1			
		5.5	0.1			
			3.0	0.50	V	(Note 2) $V_{IN} = V_{IL}$ or $V_{IH}$ $I_{OL} = 12 \text{ mA}$ $I_{OL} = 24 \text{ mA}$ $I_{OL} = 24 \text{ mA}$
			4.5	0.50		
			5.5	0.50		
$I_{IN}$	Maximum Input Leakage Current	5.5	$\pm 1.0$	$\mu A$	$V_I = V_{CC}, \text{ GND}$	
$I_{OZ}$	Maximum TRI-STATE Current	5.5	$\pm 5.0$	$\mu A$	$V_I (\text{OE}) = V_{IL}, V_{IH}$ $V_I = V_{CC}, \text{ GND}$ $V_O = V_{CC}, \text{ GND}$	

### DC Characteristics for 'AC Family Devices (Continued)

Symbol	Parameter	V <sub>CC</sub> (V)	54AC	Units	Conditions
			T <sub>A</sub> = -55°C to +125°C		
			Guaranteed Limits		
I <sub>OLD</sub>	Minimum Dynamic	5.5	50	mA	V <sub>OLD</sub> = 1.65V Max
I <sub>OHD</sub>	Output Current (Note 3)	5.5	-50	mA	V <sub>OHD</sub> = 3.85V Min
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	80.0	μA	V <sub>IN</sub> = V <sub>CC</sub> or GND

**Note 2:** All outputs loaded; thresholds on input associated with output under test.

**Note 3:** Maximum test duration 2.0 ms, one output loaded at a time.

**Note 4:** I<sub>IN</sub> and I<sub>CC</sub> @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V<sub>CC</sub>.  
I<sub>CC</sub> for 54AC @ 25°C is identical to 74AC @ 25°C.

### DC Characteristics for 'ACT Family Devices

Symbol	Parameter	V <sub>CC</sub> (V)	54ACT	Units	Conditions
			T <sub>A</sub> = -55°C to +125°C		
			Guaranteed Limits		
V <sub>IH</sub>	Minimum High Level Input Voltage	4.5	2.0	V	V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> - 0.1V
		5.5	2.0		
V <sub>IL</sub>	Maximum Low Level Input Voltage	4.5	0.8	V	V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> - 0.1V
		5.5	0.8		
V <sub>OH</sub>	Minimum High Level Output Voltage	4.5	4.4	V	I <sub>OUT</sub> = -50 μA  (Note 5) V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> I <sub>OH</sub> = -24 mA I <sub>OH</sub> = -24 mA
		5.5	5.4		
		4.5	3.70		
V <sub>OL</sub>	Maximum Low Level Output Voltage	5.5	4.70	V	I <sub>OUT</sub> = 50 μA  (Note 5) V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> I <sub>OL</sub> = 24 mA I <sub>OL</sub> = 24 mA
		4.5	0.1		
		5.5	0.1		
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	±1.0	μA	V <sub>I</sub> = V <sub>CC</sub> , GND
I <sub>OZ</sub>	Maximum TRI-STATE Current	5.5	±5.0	μA	V <sub>I</sub> = V <sub>IL</sub> , V <sub>IH</sub> V <sub>O</sub> = V <sub>CC</sub> , GND
I <sub>CCT</sub>	Maximum I <sub>CC</sub> /Input	5.5	1.6	mA	V <sub>I</sub> = V <sub>CC</sub> - 2.1V
I <sub>OLD</sub>	Minimum Dynamic	5.5	50	mA	V <sub>OLD</sub> = 1.65V Max
I <sub>OHD</sub>	Output Current (Note 6)	5.5	-50	mA	V <sub>OHD</sub> = 3.85V Min
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	80.0	μA	V <sub>IN</sub> = V <sub>CC</sub> or GND

**Note 5:** All outputs loaded; thresholds on input associated with output under test.

**Note 6:** Maximum test duration 2.0 ms, one output loaded at a time.

**Note 7:** I<sub>CC</sub> for 54ACT @ 25°C is identical to 74ACT @ 25°C.

## AC Electrical Characteristics

Symbol	Parameter	V <sub>CC</sub> (V) (Note 8)	54AC		Units	Fig. No.
			T <sub>A</sub> = -55°C to +125°C C <sub>L</sub> = 50 pF			
			Min	Max		
t <sub>PLH</sub>	Propagation Delay I <sub>n</sub> to $\bar{Z}_n$	3.3	1.0	12.0	ns	
		5.0	1.0	9.5		
t <sub>PHL</sub>	Propagation Delay I <sub>n</sub> to $\bar{Z}_n$	3.3	1.0	10.5	ns	
		5.0	1.0	7.5		
t <sub>PLH</sub>	Propagation Delay S to $\bar{Z}_n$	3.3	1.0	15.0	ns	
		5.0	1.0	11.5		
t <sub>PHL</sub>	Propagation Delay S to $\bar{Z}_n$	3.3	1.0	14.0	ns	
		5.0	1.0	10.5		
t <sub>PZH</sub>	Output Enable Time	3.3	1.0	11.5	ns	
		5.0	1.0	9.0		
t <sub>PZL</sub>	Output Enable Time	3.3	1.0	10.5	ns	
		5.0	1.0	8.5		
t <sub>PHZ</sub>	Output Disable Time	3.3	1.0	11.5	ns	
		5.0	1.0	9.5		
t <sub>PLZ</sub>	Output Disable Time	3.3	1.0	10.5	ns	
		5.0	1.0	8.5		

**Note 8:** Voltage Range 3.3 is 3.3V ±0.3V  
Voltage Range 5.0 is 5.0V ±0.5V

## AC Electrical Characteristics

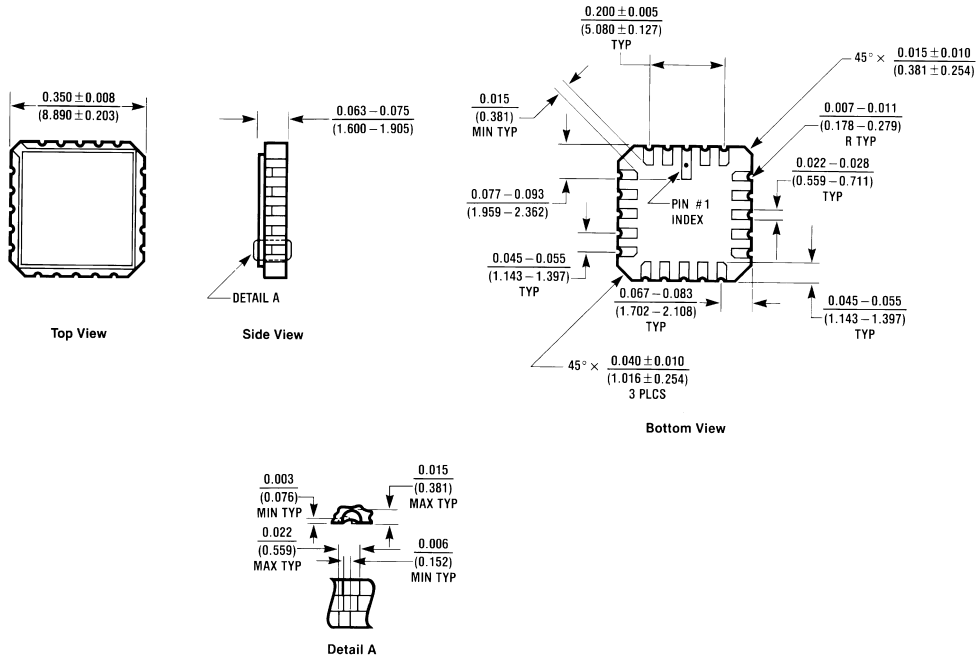
Symbol	Parameter	V <sub>CC</sub> (V) (Note 9)	54ACT		Units	Fig. No.
			T <sub>A</sub> = -55°C to +125°C C <sub>L</sub> = 50 pF			
			Min	Max		
t <sub>PLH</sub>	Propagation Delay I <sub>n</sub> to $\bar{Z}_n$	5.0	1.0	10.5	ns	
t <sub>PHL</sub>	Propagation Delay I <sub>n</sub> to $\bar{Z}_n$	5.0	1.0	9.0	ns	
t <sub>PLH</sub>	Propagation Delay S to $\bar{Z}_n$	5.0	1.0	13.0	ns	
t <sub>PHL</sub>	Propagation Delay S to $\bar{Z}_n$	5.0	1.0	12.0	ns	
t <sub>PZH</sub>	Output Enable Time	5.0	1.0	10.5	ns	
t <sub>PZL</sub>	Output Enable Time	5.0	1.0	10.0	ns	
t <sub>PHZ</sub>	Output Disable Time	5.0	1.0	10.5	ns	
t <sub>PLZ</sub>	Output Disable Time	5.0	1.0	10.0	ns	

**Note 9:** Voltage Range 5.0 is 5.0V ±0.5V

## Capacitance

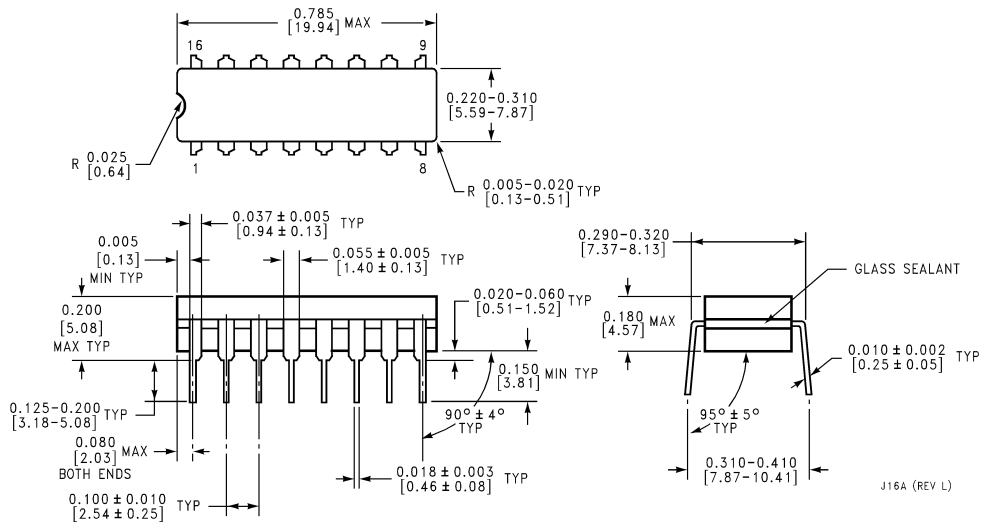
Symbol	Parameter	Typ	Units	Conditions
C <sub>IN</sub>	Input Capacitance	4.5	pF	V <sub>CC</sub> = OPEN
C <sub>PD</sub>	Power Dissipation Capacitance	55.0	pF	V <sub>CC</sub> = 5.0V

**Physical Dimensions** inches (millimeters) unless otherwise noted



E20A (REV D)

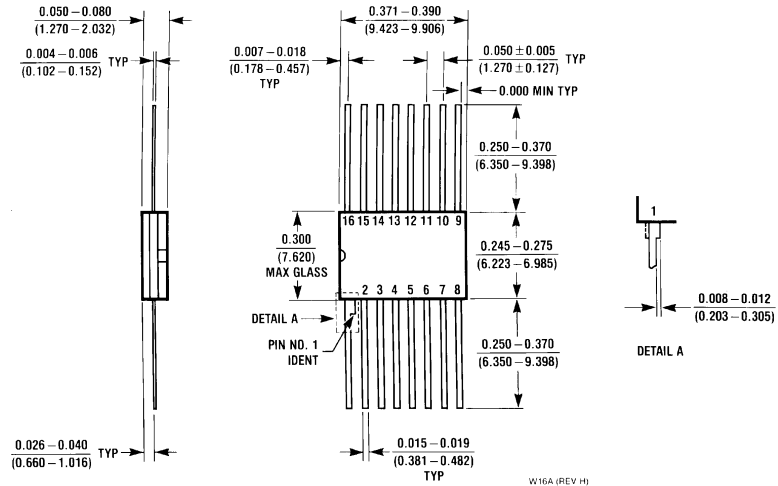
**20 Terminal Ceramic Leadless Chip Carrier (L)**  
**NS Package Number E20A**



J16A (REV L)

**16-Lead Ceramic Dual-In-Line Package (D)**  
**NS Package Number J16A**

**Physical Dimensions** inches (millimeters) unless otherwise noted (Continued)



**16-Lead Ceramic Flatpak (F)  
NS Package Number W16A**

**LIFE SUPPORT POLICY**

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



**National Semiconductor Corporation**  
Americas  
Tel: 1-800-272-9959  
Fax: 1-800-737-7018  
Email: support@nsc.com

www.national.com

**National Semiconductor Europe**  
Fax: +49 (0) 1 80-530 85 86  
Email: europe.support@nsc.com  
Deutsch Tel: +49 (0) 1 80-530 85 85  
English Tel: +49 (0) 1 80-532 78 32  
Français Tel: +49 (0) 1 80-532 93 58  
Italiano Tel: +49 (0) 1 80-534 16 80

**National Semiconductor Asia Pacific Customer Response Group**  
Tel: 65-2544466  
Fax: 65-2504466  
Email: sea.support@nsc.com

**National Semiconductor Japan Ltd.**  
Tel: 81-3-5620-6175  
Fax: 81-3-5620-6179